The 18th International Conference on Crystal Growth and Epitaxy

ICCGE-18



Nagoya, Japan August 7th - 12th, 2016

Venue Nagoya Congress Center

Abstract Deadline

March 18th, 2016

http://www.iccge18.jp/

in conjunction with The 16th International Summer School on Crystal Growth

ISSCG-16 Lake Biwa, Shiga, Japan August 1st - 7th, 2016

Venue Doshisha Biwako Retreat Center http://www.iccge18.jp/isscg16/





Scope of ICCGE-18

The 18th International Conference on Crystal Growth and Epitaxy (ICCGE-18) will be held on August 7-12, 2016, in Nagoya, Japan. The conference will provide presentation and discussion sessions on recent research and development activities in all aspects of crystal growth. The conference will consist of general and topical sessions. Topical sessions are planned for nanostructure fabrication, magnetic semiconductors, wide-bandgap semiconductors and other topics, while the general sessions may include the theory of crystal growth, pattern formation, the bulk crystal growth of semiconductors and oxides, protein crystal growth and epitaxial thin-film growth. The technical program will include both oral and poster sessions, as well as plenary and invited talks to provide a complete picture of the latest developments in the field. Some of the sessions will be jointly organized with the IUCR Committee on Crystal Growth.



Prof. I. Akasaki NAGOYA UNIV.

Nagoya Congress Center

Toyoda Auditorium

Plenary Speakers

Isamu Akasaki (Meijo University, Japan) 2014 Nobel Prize Laureate Hiroshi Amano (Nagoya University, Japan) 2014 Nobel Prize Laureate Daan Frenkel (University of Cambridge, UK) Zbigniew Galazka (IKZ Berlin, Germany) Zhanggui Hu and Chuangtian Chen (Chinese Academy of Sciences, China) Thomas Kuech (University of Wisconsin, USA) Frances Ross (IBM Yorktown Heights, USA)

Important Dates

December 1, 2015	Start of abstract submission
January 12, 2016	Start of registration
March 18, 2016	Abstract submission deadline
April 30, 2016	Notification of abstract acceptance
May 1, 2016	Start of proceedings manuscript submission
May 31, 2016	End of early registration
July 1, 2016	Conference schedule announced
July 15, 2016	Deadline of proceedings manuscript submission
July 25, 2016	End of on-line registration
August 7, 2016	Beginning of ICCGE-18

Category Plan & Category Chairs

G02 G03 G04 G05	Fundamentals of Nucleation and Crystal Growth Makio Uwaha (Aichi Inst. of Tech.) / Peter Vekilov (Univ. of Houston) Surfaces and Interfaces Gen Sazaki (Hokkaido Univ.) / Elias Vlieg (Radboud Univ. Nijmegen) Nanomaterials and Low Dimensional Structures Lutz Geelhaar (Paul-Drude-Institut für Festkörperelektronik) / Jyunichi Motohisa (Hokkaido Univ.) / Shigeya Naritsuka (Meijo Univ.) Thin Films and Epitaxial Growth Joan Redwing (Penn State Univ.) / Masakazu Sugiyama (The Univ. of Organic and Biological Crystallization Garcia Ruiz (Univ. of Granada) / Yoshihisa Suzuki (Tokushima Univ.) / Junpei Yamanaka (Nagoya City Univ.) Bulk Crystal Growth
G03 G04 G05	Gen Sazaki (Hokkaido Univ.) / Elias Vlieg (Radboud Univ. Nijmegen) Nanomaterials and Low Dimensional Structures Lutz Geelhaar (Paul-Drude-Institut für Festkörperelektronik) / Jyunichi Motohisa (Hokkaido Univ.) / Shigeya Naritsuka (Meijo Univ.) Thin Films and Epitaxial Growth Joan Redwing (Penn State Univ.) / Masakazu Sugiyama (The Univ. of Organic and Biological Crystallization Garcia Ruiz (Univ. of Granada) / Yoshihisa Suzuki (Tokushima Univ.) / Junpei Yamanaka (Nagoya City Univ.)
G04 G05	Nanomaterials and Low Dimensional Structures Lutz Geelhaar (Paul-Drude-Institut für Festkörperelektronik) / Jyunichi Motohisa (Hokkaido Univ.) / Shigeya Naritsuka (Meijo Univ.) Thin Films and Epitaxial Growth Joan Redwing (Penn State Univ.) / Masakazu Sugiyama (The Univ. of Organic and Biological Crystallization Garcia Ruiz (Univ. of Granada) / Yoshihisa Suzuki (Tokushima Univ.) / Junpei Yamanaka (Nagoya City Univ.)
G05	Jyunichi Motohisa (Hokkaido Univ.) / Shigeya Naritsuka (Meijo Univ.) Thin Films and Epitaxial Growth Joan Redwing (Penn State Univ.) / Masakazu Sugiyama (The Univ. of Organic and Biological Crystallization Garcia Ruiz (Univ. of Granada) / Yoshihisa Suzuki (Tokushima Univ.) / Junpei Yamanaka (Nagoya City Univ.)
G05	Joan Redwing (Penn State Univ.) / Masakazu Sugiyama (The Univ. of Organic and Biological Crystallization Garcia Ruiz (Univ. of Granada) / Yoshihisa Suzuki (Tokushima Univ.) / Junpei Yamanaka (Nagoya City Univ.)
	Garcia Ruiz (Univ. of Granada) / Yoshihisa Suzuki (Tokushima Univ.) / Junpei Yamanaka (Nagoya City Univ.)
G06	•
900	
	Sonia Baldochi (Nuclear and Energy Research Institute, IPEN–CNEN/SP), Matthias Bickermann (IKZ) / Akira Yoshikawa (Tohoku Univ.)
G07	Defect Formation Janakiraman Kumar (Anna Univ.) / Ichiro Yonenaga (Tohoku Univ.)
G08	Advanced Growth Technologies
	Geetha Balakrishnan (Univ. of Warwick) /
000	Zhenxiang Cheng (Univ. of Wollongong) / Hideo Kimura (NIMS)
	In situ Observation and Characterization Jim De Yoreo (PNNL) / Katsuo Tsukamoto (Osaka Univ. / Tohoku Uni
G10	External Fields, Microgravity Aleksandar Ostrogorsky (Illinois Inst. of Tech.) / Satoshi Uda (Tohoku
G11	Industrial Crystallization François Puel (Paris Saclay Univ.) / Kiyoshi Shimamura (NIMS)
	ical Session (Materials & Applications)
T01	III-V Semiconductors Michal Bockowski (Inst. of High Pressure Physics) / Takashi Matsuoka (Tohoku
T02	Group IV Semiconductors Christian Reimann (Fraunhofer IISB) / Noritaka Usami (Nagoya Uni
т03	2D Materials Thomas Seyller (Tech. Univ. Chemnitz) / Satoru Tanaka (Kyushu Univ.
T04	II-VI and Oxide Materials Igor Avetissov (D. Mendeleev Univ. of Chemical Technology of Russia) / Hitoshi Tabata (The Univ. of Tokyo)
T05	Materials for Spintronics
	Shigehiko Hasegawa (Osaka Univ.) / Jens Herfort (Paul-Drude-Institut für Festkörperelektronik) / Shinobu Ohya (The Univ. of Tokyo)
T06	Materials for Optical Devices Gérard Aka (Chimie ParisTech Institute) / Masashi Yoshimura (Osaka L
T07	Materials for Electron Devices Atsushi Tsukazaki (Tohoku Univ.) / Markus Weyers (Ferdinand-Braun-Inst Andrea Zappettini (IMEM-CNR)
T08	Materials for Organic Devices and Bio Applications Christian Leo Kloc (Nanyang Tech. Univ.) / Yuji Yoshida (AIST)
т09	Nitride Semiconductors Izabella Grzegory (Inst. of High Pressure Physics) / Yasushi Nanishi (Ritsumeikan U
T10	Silicon Carbide Peder Bergman (Linköping Univ.) / Toru Ujihara (Nagoya Univ.)
Late	nt Session

Committees

Organizing Committee

Co-Chairs	Koichi Kakimoto (Kyushu University) Yasuhiko Arakawa (The University of Tokyo)		
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N. Akutsu (Japan) S. Baldochi (Brazil) A. A. Chernov (USA) F. M. Costa (Portugal) J. Derby (USA) P. P. Fedorov (Russia) J. Friedlich (Germany) J. M. Garcia-Ruiz (Spain) A. Ibanez (France) K. Kakimoto (Japan) S. Krukowski (Poland) A. Moreno (Mexico) S. Nishizawa (Japan) M.Pons (France) F. Puel (France) K. Roberts (GB) C. Frank-Rotsch (Germany) P. Rudolph (Germany) J. Speck (USA) K. Tsukamoto (Japan) M.Uwaha (Japan) D. Vizman (Romania) J. Wang (China) R. Yakimova (Sweden) A. Zappettini (Italy)

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P

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Abstract Submission

Abstract Deadline March 18th, 2016

Abstract submission of contributed papers is possible only through the conference website. Please refer to the detailed information on the abstract format on the website.

http://www.iccge18.jp/abstracts.html

Late News Papers

A limited number of papers describing the most up-to-date results will be accepted as Late News Papers. Abstracts for these papers should be prepared using the same guidelines as those for regular papers.

Proceedings

The conference proceedings will be published as a special issue of the Journal of Crystal Growth (JCG). The authors of successfully accepted abstracts are requested to submit the manuscripts to the proceedings.

IOCG Prizes

The Frank Prize is awarded for significant fundamental contributions to the field of crystal growth. The Laudise prize is presented for significant technological contributions to the field of crystal growth. The Schieber prize is awarded to a young author to recognize his or her outstanding scientific publications in the field of crystal growth.

http://www.iocg.org/prizes/index.html

Social Activities

Welcome Reception (Sunday evening, August 7)

Excursion (Wednesday, August 10)

- Ise Jingu (Ise Grand Shrine)
- Toyota Automobile Museum
- Atsuta Shrine & Nagoya Asahi Brewery Tour
- Port of Nagoya Public Aquarium & SCMAGLEV and Railway Park

Banquet (Thursday evening, August 11)

Venue: Nagoya Marriott Associa Hote

Registration

All attendees and presenters of contributed papers are subject to the relevant registration fees.

Category	Until May 31, 2016	From June 1, 2016		
Regular	JPY 80,000	JPY 90,000		
Student	JPY 40,000	JPY 50,000		
Accompany	JPY 10,000	JPY 10,000		
Excursion on Aug.10	JPY 5,000			
Banquet on Aug. 11	JPY 8,000			

Conference registration fees include

Regular Participants	 Attendance of all the technical sessions. Conference documents and proceedings. Invitation to the Welcome Reception. Lunches and coffee breaks. 	
Students	- As for Regular Participants, except for Proceedings.	
Accompanying Persons	 Invitation to the Welcome Reception. Lunches and coffee breaks. 	

Payment	Payment should be made by no later than July 25, 2016. - No reservation will be confirmed in the absence of payment. - All payment must be in Japanese yen. - Please pay by credit card if you live overseas.			
	Payment Methods			
	(1) Credit Card Online VISA, MasterCard, American Express, Diners Club or JCB only.			
	 (2) Bank Transfer Please contact the person in charge. ■ JTB Western Japan, Corp. Corporate Sales Central Office ■ Email: j_hasegawa109@west.jtb.jp 			
Cancellation				
	We will charge the following cancellation fee			
	Before May 31, 2016 JPY 5,000			
	On or after June 1, 2016 100% of the registration fee / No Refund			

Further details will be provided on the conference website.

http://www.iccge18.jp/registration.html

Accommodation

Nagoya Marriott Associa Hotel provides comfortable accommodation at reasonable rates. The following hotels in downtown Nagoya are also available.

- ANA Crowne Plaza Hotel Grand Court Nagoya
- Nagoya Kanayama Hotel
- Cypress Garden Hotel

Further details will be provided on the conference website.

http://www.iccge18.jp/accommodation.html

Official Registration Desk & Travel Agent

JTB Western Japan Corp. has been appointed to staff the official registration desk during the conference and will handle registration and hotel accommodation.

JTB Western Japan Corp. Corporate Sales Central Office (Convention, Meeting and Event Team)

Address	: 11F Hommachi cross bldg.,
	3-1-8, Minami Kyuhoji-cho, Chuo-ku, Osaka, Japan, 541-0058
Phone:	+81-6-6252-2830 (Weekday 9:30-17:30)
Fax:	+81-6-6252-2695

Email: j_hasegawa109@west.jtb.jp

Passport & Visa

All foreign visitors entering Japan must possess a valid passport. Participants from countries requiring a visa to enter Japan should obtain one from the nearest Japanese embassy or consulate in good time. If documents to be issued by the conference committee are necessary for the visa application (invitation letter, etc.), please contact the ICCGE-18 secretary or ISSCG-16 secretary.



Welcome to Nagova

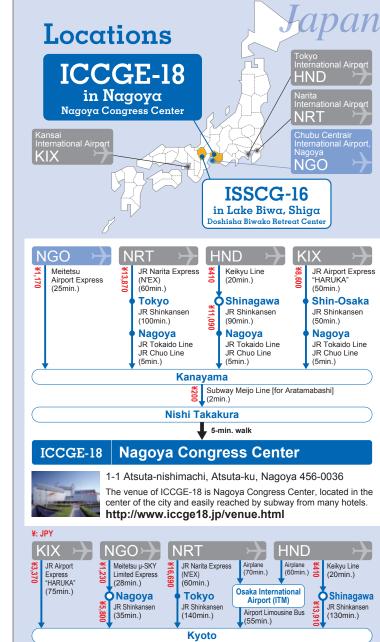




Noritake Museum

Nagoya TV Tower and Oasis 21

Nagoya Castle



JR Kosei Line (33min.) by Special Rapid Train

Kita-Komatsu

🚽 25-min. walk north

ISSCG-16 Doshisha Biwako Retreat Center



179 Kitakomatsu, Otsu-shi, Shiga

The venue of ISSCG-16 is Doshisha Biwako Retreat Center http://www.iccge18.jp/isscg16/venue.html

Scope of ISSCG-16

Researchers playing active roles in extending the frontiers of a wide range of fields in crystal growth will give lectures on a wide array of topics ranging from instructive topics to the latest topics. Students will therefore have an opportunity to systematically learn about crystal growth from its fundamentals to its applications. All the lecturers and students will stay in the same accommodation for six days. The friendly and homely atmosphere will be a valuable opportunity for both lecturers and students to share information and learn from each other.

Features

In addition to stimulating lectures, we are also planning to hold five courses to promote enthusiastic discussion, including experiments and simulations. Lecturers will also participate in the discussion. Through such discussion, students will obtain a deeper understanding of crystal growth. We also plan to hold poster presentations in which students can have in-depth discussions with lecturers and other participants.

Memories of ISSCG-11

ISSCG-11(2001) was held at the same venue of Doshisha Biwako Retreat Center. The school facility has not changed much except for the planting of a camphor tree, by the participants during the School to commemorate the event.







The plate of ISSCG-11, 24-29 July 2001 and Robert Sekerka (7th President of IOCG), Tatau Nishinaga (6th), Raymond Kern (4th), and Alexander Chernov (8th) from left to right in front of the planted camphor tree.

Registration

Start of registration

January 12th, 2016

End of early registration

May 31th, 2016

The number of School attendees is limited to 120. Participants are encouraged to register as soon as possible in order to guarantee participation. Registration will be accepted on a first-come-first-served basis. Payment is allowed only by credit card using a web payment system.

Registration fees

Category	Until May 31, 2016	From June 1, 2016	
Regular	JPY 80,000	JPY 90,000	
Student	JPY 60,000	JPY 70,000	
Accompanying person	JPY 60,000	JPY 70,000	

Registration fees include

Regular and student participants	- attendance of all lectures - accommodation (six nights) - all meals and banquet - excursion - School textbook
Accompanying persons	 accommodation (six nights) all meals and banquet excursion

Accommodation

In Doshisha Biwako Retreat Center, the number of western-style single rooms is limited. Hence, five to six attendees (other than lecturers) will share one Japanese-style room. An attendee will use a set of futons (Japanese mattresses and quilts) spread on tatami mats. Such Japanese-style accommodation is beneficial for forming close relationships among attendees.

In this facility, attendees use a shared Japanese-style bathroom. Attendees also need to provide their own nightwear and toiletries.

If an attendee has accompanying persons, please contact the organizing committee* as soon as possible since the number of family-use rooms is also very limited.

*Organizing Committee isscg16@iccge18.jp

School website

http://www.iccge18.jp/isscg16/

Lecturers and Titles of Lectures [Tentative]

1.5 Hour Lectures

Tatau Nishinaga (University of Tokyo, Japan) 2004 IOCG Laudise Prize-winner "Thermodynamics"

Makio Uwaha (Aichi Institute of Technology, Japan) "BCF theory"

Jim De Yoreo (PNNL, USA) 2010 IOCG Laudise Prize-winner "In-situ observation of nucleation and growth processes by TEM observation"

Peter Rudolph (CTC, Germany) "Fundamentals and engineering of defects"

Hiroshi Amano (Nagoya University, Japan) 2014 Novel Prize laureate

"LED GaN growth"

Sumio lijima (Meijo University, Japan) "Carbon nanotube"

Katsuo Tsukamoto (Osaka University / Tohoku University, Japan) 2013 IOCG Frank Prize-winner

"In-situ observation and growth mechanisms"







Experimental Practice and Discussion International Presummer School on Crystal Growth held at DBRC in 2015





1.0 Hour Lectures (fundamental)

Peter G. Vekilov (University of Houston, USA) "Nucleation of protein crystals"

Elias Vlieg (University of Nijmegen, The Netherlands) "Characterization of surfaces and interfaces"

Olivier Pierre-Louis (ILM, France) "Solid-state wetting and de-wetting"

Hiroki Hibino (Kwansei Gakuin University, Japan) "In-situ observation of step dynamics and graphene"

Juan M. Garcia-Ruiz (University of Granada, Spain) "Mineral crystallization"

Hiroaki Imai (Keio University, Japan) "Growth of meso-crystals"

Mu Wang (Nanjing University, China) "Complex (periodic) pattern formation & its function"

1.0 Hour Lectures (application)

Koichi Kakimoto (Kyushu University, Japan) "Si bulk crystals"

Jeffrey J. Derby (University of Minnesota, USA) "Fluid dynamics simulation"

Thomas Kuech (University of Wisconsin, USA) "III-V semiconductor crystals"

Tsunenobu Kimoto (Kyoto University, Japan) "Silicon carbide crystals"

Shigeya Naritsuka (Meijo University, Japan) "Lateral growth"

Christopher Palmstrom (University of California, USA) "Heusler materials and spintronics"

Makoto Kasu (Saga University, Japan) "Diamond epitaxy"

Practice Courses of Experiments and Simulations

1. In-situ real time observation of colloidal crystallization

Junpei Yamanaka (Nagoya City University, Japan) Tsutomu Sawada (National Institute for Materials Science, Japan) Yoshihisa Suzuki (Tokushima University, Japan) Jun Nozawa (Tohoku University, Japan)

Observing crystal growth processes in computer simulations

Hiroki Nada (AIST, Japan) Hitoshi Miura (Nagoya City University, Japan) Jun Kawano (Hokkaido University, Japan)

Assembling interferometers and in-situ observation of ambient phases and solid-liquid interfaces Yuki Kimura (Hokkaido University, Japan) 2013 IOCG Schieber Prize-winner Kenta Murayama (Nagoya University, Japan)

Tomoya Yamazaki (Hokkaido University, Japan)

In-situ observation of crystal surfaces by optical microscopy

Gen Sazaki (Hokkaido University, Japan) Ken Nagashima (Hokkaido University, Japan) Ken-ichiro Murata (Hokkaido University, Japan)

5. Polymorphism of edible fat crystals Hironari Hondoh (Hiroshima University, Japan) Satoru Ueno (Hiroshima University, Japan)

Poster Presentations

Students are encouraged to give poster presentations, during which they can have in-depth discussions with lecturers and other attendees. The deadline for the registration of poster presentations is **May 31, 2016**.

Important Dates

January 12, 2016 Start of registration

May 31, 2016

End of early registration and end of registration of poster presentations

Committees

Organizing Committee Chair Gen Sazaki (Hokkaido University) Vice Chairs Hiroki Nada (AIST) Shigeya Naritsuka (Meijo University) Treasurer Chief Ken Nagashima (Hokkaido University) Member Jun Kawano (Hokkaido University) General Affairs Chief Jiro Nishinaga (AIST) Members Motoaki Iwaya (Meijo University) Yuki Kimura (Hokkaido University) Public Affairs Chief Hitoshi Miura (Nagoya City University) Members Ryuji Katayama (Tohoku University) Mihoko Maruyama (Osaka University) Grants Shigeya Naritsuka (Meijo University) Publication Hiroki Nada (AIST) Local Arrangement Naoki Ohtani (Doshisha University) Shinzo Yoshikado (Doshisha University) Toshitaka Nakada (Ritsumeikan University)

Advisors Tadashi Ohachi (Doshisha University) Koichi Kakimoto (Kyushu University)

ISSCG-16 Program (Schedule) [Tentative]

August, 2016 (Doshisha Biwako Retreat Center (DBRC))

	1 (Mon)	2 (Tue)	3 (Wed)	4 (Thr)	5 (Fri)	6 (Sat)	7 (Sun)
9:00 -10:30		L-4	L-10	L-16	L-18	L-20	Leaving
10:45 -11:45		L-5	L-11	L-17	L-19	L-21	(Registration of ICCGE-18
12:00 -13:00		Lunch	Lunch	Lunch	Lunch	Lunch	opens from 15:00 on 7th)
13:15 -14:15	Registration	L-6	L-12			L-22	
14:30 -15:30	L-1	L-7	L-13	Excursion	Experimental	L-23	
15:45 -16:45	L-2	L-8	L-14		Session	L-24	
17:00 -18:00	L-3	L-9	L-15			L-25	
18:00 -20:00	Decention	Dinner	Dinner		Dinner	Demoust	
20:00 -21:00	Reception	Poster 1	Poster 2	\geq	Poster 3	Banquet	

ICCGE-18 Program at a Glance [Tentative]

August, 2016 (Nagoya)

	7 (Sun)	8 (Mon)	9 (Tue)	10 (Wed)	11 (Thu)	12 (Fri)
8:00		Registration	Registration	Registration	Registration	Registration
9:00		Opening	Plenary 2, 3	Plenary 4, 5	Award 1, 2, 3	FR 1 8 parallel
10:00		Plenary 1				
		Coffee Break	Coffee Break	Coffee Break	Coffee Break	Coffee Break
11:00		Mo 1 6 parallel	Tu 1 6 parallel	We 1 8 parallel	Th 1 6 parallel	Plenary 6, 7
12:00	JACG	+ 2 joint session	+ 2 joint session	Excursion	+ 2 joint session	Closing
13:00		JCG Lunch Editor	Lunch IOCG Exec. Meeting		IOCG Lunch Council	Closing
14:00		Meeting			Meeting	
15:00	Meeting	Mo 2 8 parallel	Tu 2 8 parallel		IOCG Assembly	
					Coffee Break	
16:00	Registration				Poster 3	
		Coffee Break	Coffee Break			
17:00		Mo 3 8 parallel	Tu 3 8 parallel			
18:00	Welcome Reception					
19:00						
20:00		Poster 1	Poster 2		Banquet	

Exhibition & Sponsorship

ICCGE-18 Exhibition & Advertising Contact (for application)

Exhibition & Advertising Secretariat

Email: iccge18@ktis.jp

Phone: +81-6-4708-7114

Fax: +81-6-4708-7324

*Please visit ICCGE official web site for further details. http://www.iccge18.jp/exhibitions_en.html

ICCGE-18 Sponsorship Contact

ICCGE-18 Secretariat Email: secretariat@iccge18.jp

Further Information

Please visit the website for details on registration, exhibitions and other information.

ICCGE-18

Yusuke Mori

- Email: secretariat@iccge18.jp
- http://www.iccge18.jp/

ISSCG-16

- Gen Sazaki
- Email: isscg16@iccge18.jp
- http://www.iccge18.jp/isscg16/